

# FDD6N20

## N-Channel UniFET™ MOSFET

200 V, 4.5 A, 800 mΩ

### Features

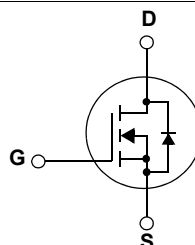
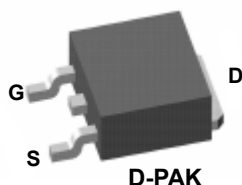
- $R_{DS(on)} = 600 \text{ m}\Omega$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 2.3 \text{ A}$
- Low Gate Charge (Typ. 4.7 nC)
- Low  $C_{rss}$  (Typ. 6.3 pF)
- 100% Avalanche Tested
- RoHS Compliant

### Applications

- LCD/LED/PDP TV
- Consumer Appliances
- Lighting
- Uninterruptible Power Supply

### Description

UniFET™ MOSFET is Fairchild Semiconductor®'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted\*

| Symbol         | Parameter                                                                    | FDD6N20                                    | Unit               |
|----------------|------------------------------------------------------------------------------|--------------------------------------------|--------------------|
| $V_{DSS}$      | Drain to Source Voltage                                                      | 200                                        | V                  |
| $V_{GSS}$      | Gate to Source Voltage                                                       | $\pm 30$                                   | V                  |
| $I_D$          | Drain Current                                                                | - Continuous ( $T_C = 25^\circ\text{C}$ )  | A                  |
|                |                                                                              | - Continuous ( $T_C = 100^\circ\text{C}$ ) |                    |
| $I_{DM}$       | Drain Current                                                                | - Pulsed (Note 1)                          | A                  |
| $E_{AS}$       | Single Pulsed Avalanche Energy                                               | (Note 2)                                   | mJ                 |
| $I_{AR}$       | Avalanche Current                                                            | (Note 1)                                   | A                  |
| $E_{AR}$       | Repetitive Avalanche Energy                                                  | (Note 1)                                   | mJ                 |
| $dv/dt$        | Peak Diode Recovery $dv/dt$                                                  | (Note 3)                                   | V/ns               |
| $P_D$          | Power Dissipation                                                            | ( $T_C = 25^\circ\text{C}$ )               | W                  |
|                |                                                                              | - Derate above $25^\circ\text{C}$          | $^\circ\text{C/W}$ |
| $T_J, T_{STG}$ | Operating and Storage Temperature Range                                      | -55 to +150                                | $^\circ\text{C}$   |
| $T_L$          | Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds | 300                                        | $^\circ\text{C}$   |

### Thermal Characteristics

| Symbol          | Parameter                                     | FDD6N20 | Unit               |
|-----------------|-----------------------------------------------|---------|--------------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case, Max.    | 3.1     | $^\circ\text{C/W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient, Max. | 110     |                    |

**Package Marking and Ordering Information**  $T_C = 25^\circ\text{C}$  unless otherwise noted

| Device Marking | Device    | Package | Reel Size | Tape Width | Quantity |
|----------------|-----------|---------|-----------|------------|----------|
| FDD6N20        | FDD6N20TM | D-PAK   | 380mm     | 16mm       | 2500     |

**Electrical Characteristics**

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--------|-----------|-----------------|------|------|------|------|
|--------|-----------|-----------------|------|------|------|------|

**Off Characteristics**

|                                |                                           |                                                                          |     |      |           |                    |
|--------------------------------|-------------------------------------------|--------------------------------------------------------------------------|-----|------|-----------|--------------------|
| $BV_{DSS}$                     | Drain to Source Breakdown Voltage         | $I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$ , $T_J = 25^\circ\text{C}$ | 200 | -    | -         | V                  |
| $\Delta BV_{DSS} / \Delta T_J$ | Breakdown Voltage Temperature Coefficient | $I_D = 250\mu\text{A}$ , Referenced to $25^\circ\text{C}$                | -   | 0.28 | -         | $V/^\circ\text{C}$ |
| $I_{DSS}$                      | Zero Gate Voltage Drain Current           | $V_{DS} = 200\text{V}$ , $V_{GS} = 0\text{V}$                            | -   | -    | 1         | $\mu\text{A}$      |
|                                |                                           | $V_{DS} = 160\text{V}$ , $T_C = 125^\circ\text{C}$                       | -   | -    | 10        |                    |
| $I_{GSS}$                      | Gate to Body Leakage Current              | $V_{GS} = \pm 30\text{V}$ , $V_{DS} = 0\text{V}$                         | -   | -    | $\pm 100$ | nA                 |

**On Characteristics**

|              |                                      |                                             |     |     |     |          |
|--------------|--------------------------------------|---------------------------------------------|-----|-----|-----|----------|
| $V_{GS(th)}$ | Gate Threshold Voltage               | $V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$  | 3.0 | -   | 5.0 | V        |
| $R_{DS(on)}$ | Static Drain to Source On Resistance | $V_{GS} = 10\text{V}$ , $I_D = 2.3\text{A}$ | -   | 0.6 | 0.8 | $\Omega$ |
| $g_{FS}$     | Forward Transconductance             | $V_{DS} = 40\text{V}$ , $I_D = 2.3\text{A}$ | -   | 2.9 | -   | S        |

**Dynamic Characteristics**

|              |                               |                                                                                 |   |     |     |    |
|--------------|-------------------------------|---------------------------------------------------------------------------------|---|-----|-----|----|
| $C_{iss}$    | Input Capacitance             | $V_{DS} = 25\text{V}$ , $V_{GS} = 0\text{V}$<br>$f = 1\text{MHz}$               | - | 170 | 230 | pF |
| $C_{oss}$    | Output Capacitance            |                                                                                 | - | 45  | 60  | pF |
| $C_{rss}$    | Reverse Transfer Capacitance  |                                                                                 | - | 6.3 | 9.5 | pF |
| $Q_{g(tot)}$ | Total Gate Charge at 10V      | $V_{DS} = 160\text{V}$ , $I_D = 6\text{A}$<br>$V_{GS} = 10\text{V}$<br>(Note 4) | - | 4.7 | 6.1 | nC |
| $Q_{gs}$     | Gate to Source Gate Charge    |                                                                                 | - | 1.2 | -   | nC |
| $Q_{gd}$     | Gate to Drain "Miller" Charge |                                                                                 | - | 2.2 | -   | nC |

**Switching Characteristics**

|              |                     |                                                                            |   |      |      |    |
|--------------|---------------------|----------------------------------------------------------------------------|---|------|------|----|
| $t_{d(on)}$  | Turn-On Delay Time  | $V_{DD} = 100\text{V}$ , $I_D = 6\text{A}$<br>$R_G = 25\Omega$<br>(Note 4) | - | 8.3  | 26.7 | ns |
| $t_r$        | Turn-On Rise Time   |                                                                            | - | 5.6  | 21.2 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time |                                                                            | - | 15   | 40   | ns |
| $t_f$        | Turn-Off Fall Time  |                                                                            | - | 12.8 | 35.5 | ns |

**Drain-Source Diode Characteristics**

|                 |                                                          |                                              |   |     |     |    |
|-----------------|----------------------------------------------------------|----------------------------------------------|---|-----|-----|----|
| I <sub>S</sub>  | Maximum Continuous Drain to Source Diode Forward Current |                                              | - | -   | 4.5 | A  |
| I <sub>SM</sub> | Maximum Pulsed Drain to Source Diode Forward Current     |                                              | - | -   | 18  | A  |
| V <sub>SD</sub> | Drain to Source Diode Forward Voltage                    | V <sub>GS</sub> = 0V, I <sub>SD</sub> = 4.5A | - | -   | 1.4 | V  |
| t <sub>rr</sub> | Reverse Recovery Time                                    | V <sub>GS</sub> = 0V, I <sub>SD</sub> = 6A   | - | 120 | -   | ns |
| Q <sub>rr</sub> | Reverse Recovery Charge                                  | dI <sub>F</sub> /dt = 100A/μs                | - | 0.4 | -   | μC |

**Notes:**

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2:  $L = 5.9\text{mH}$ ,  $I_{AS} = 4.5\text{A}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$
- 3:  $I_{SD} \leq 4.5\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$
- 4: Essentially Independent of Operating Temperature Typical Characteristics

## Typical Performance Characteristics

Figure 1. On-Region Characteristics

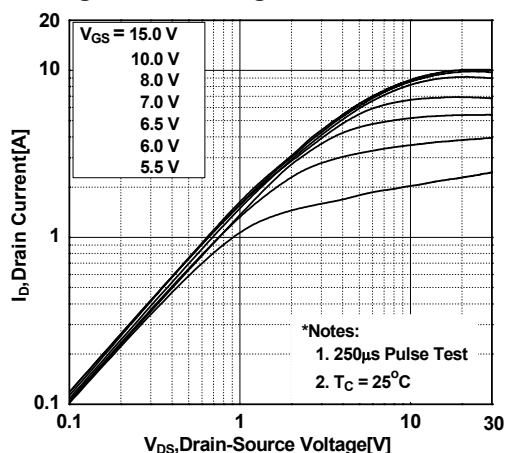


Figure 2. Transfer Characteristics

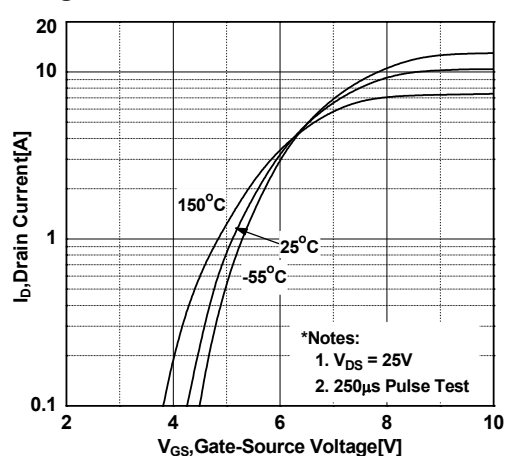


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

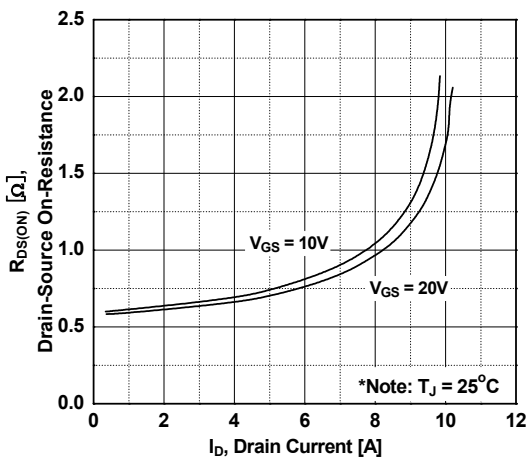


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

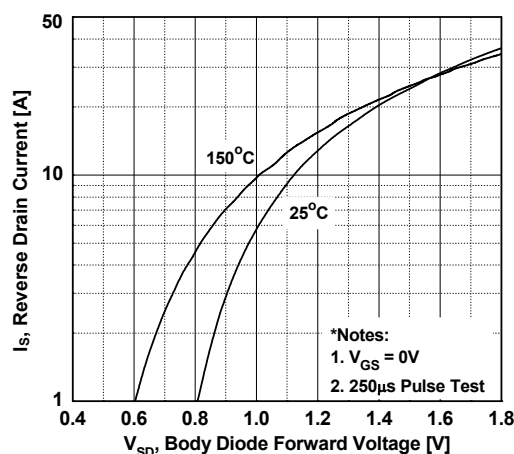


Figure 5. Capacitance Characteristics

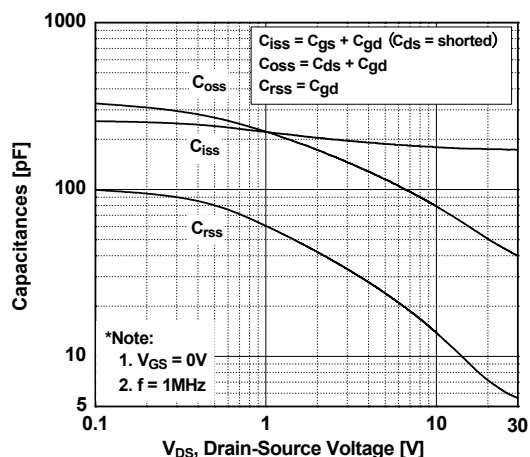
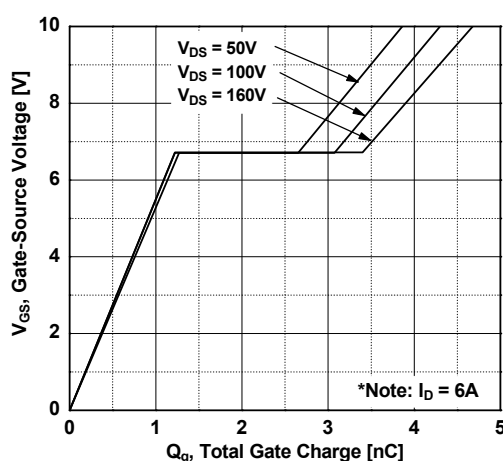
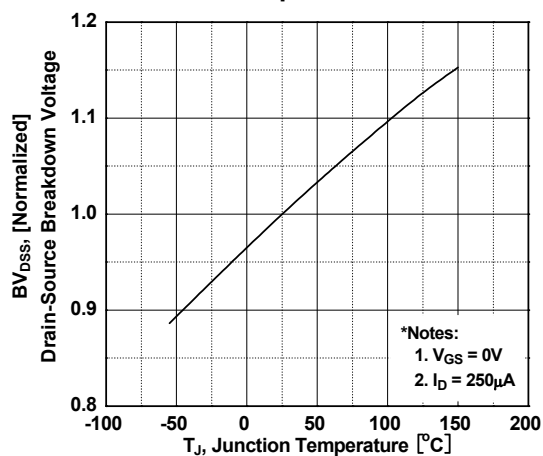


Figure 6. Gate Charge Characteristics

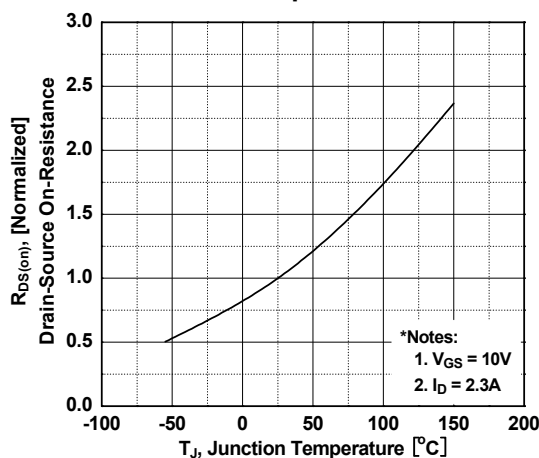


## Typical Performance Characteristics (Continued)

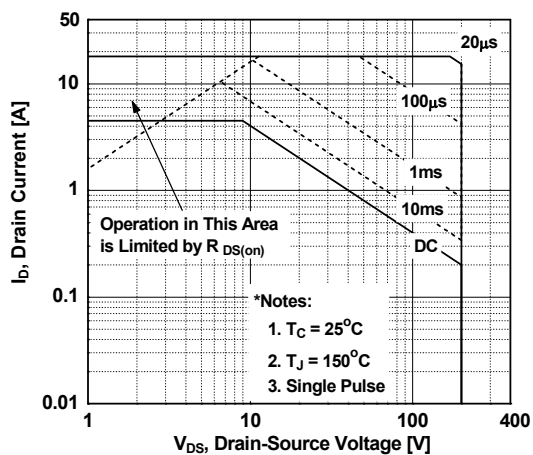
**Figure 7. Breakdown Voltage Variation vs. Temperature**



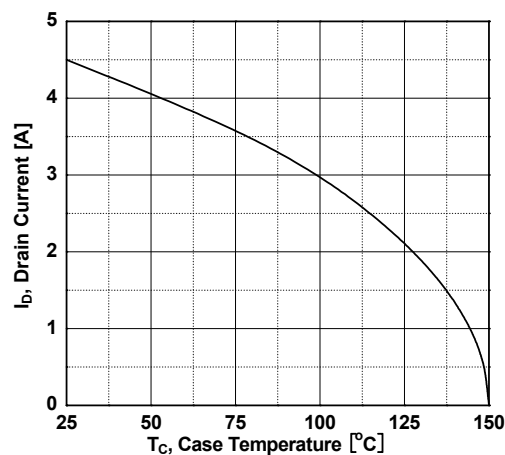
**Figure 8. On-Resistance Variation vs. Temperature**



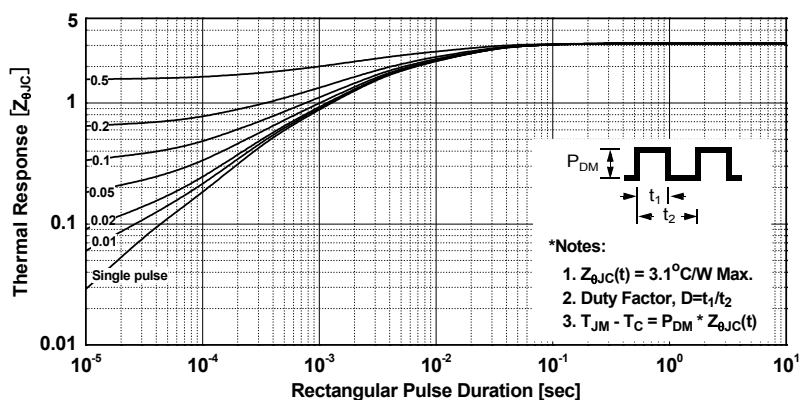
**Figure 9. Maximum Safe Operating Area**



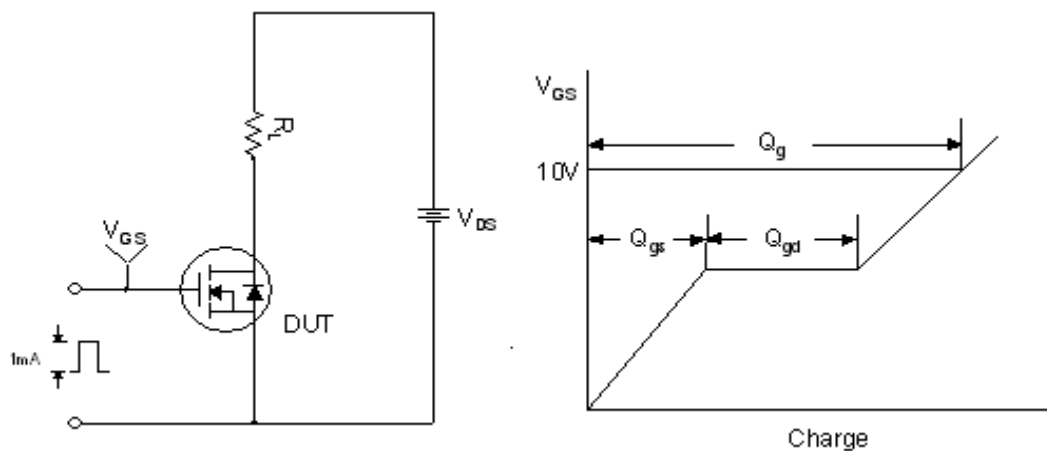
**Figure 10. Maximum Drain Current vs. Case Temperature**



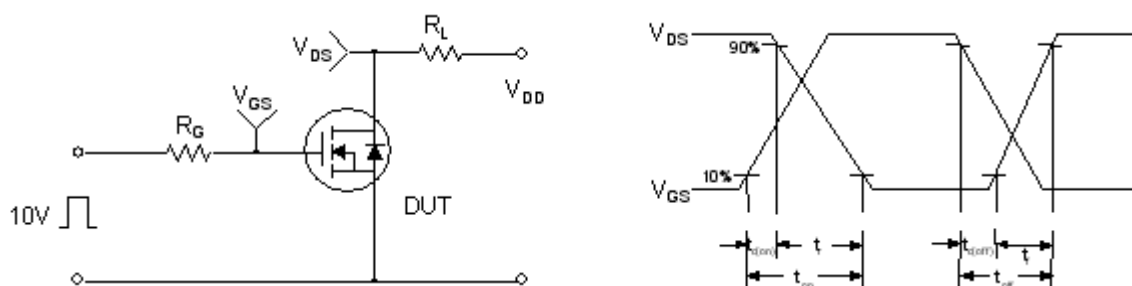
**Figure 11. Transient Thermal Response Curve**



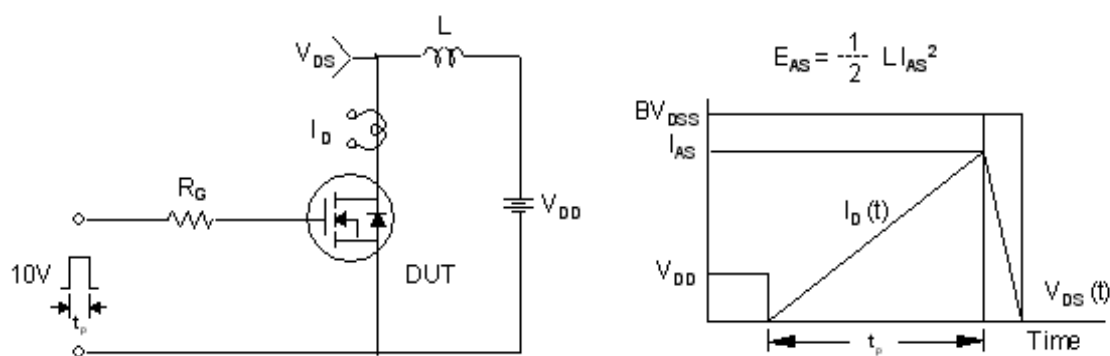
**Gate Charge Test Circuit & Waveform**



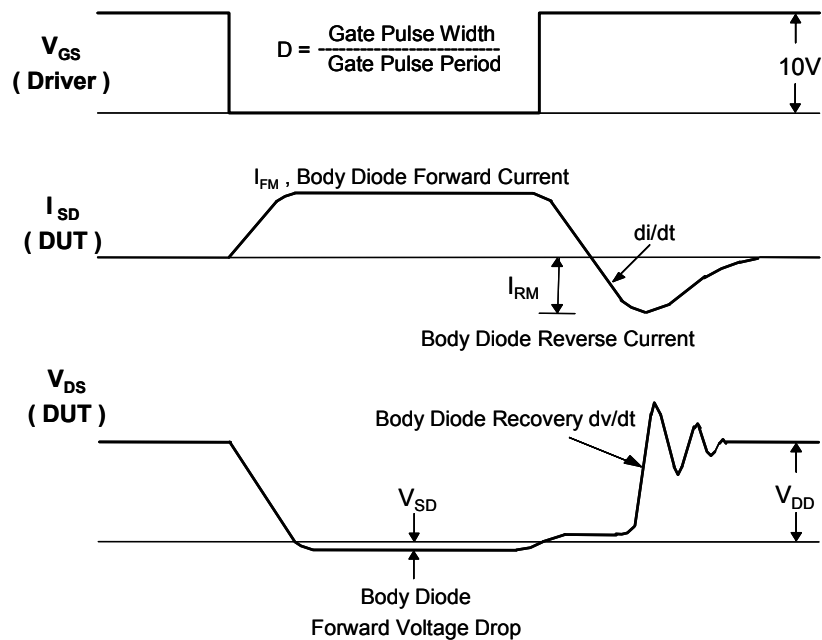
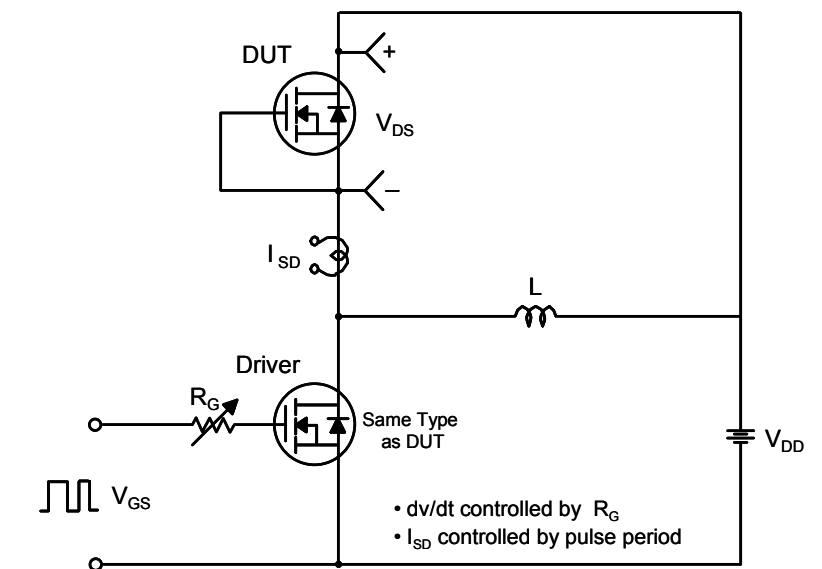
**Resistive Switching Test Circuit & Waveforms**



**Unclamped Inductive Switching Test Circuit & Waveforms**

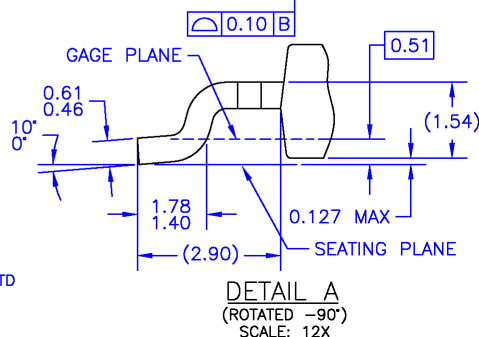
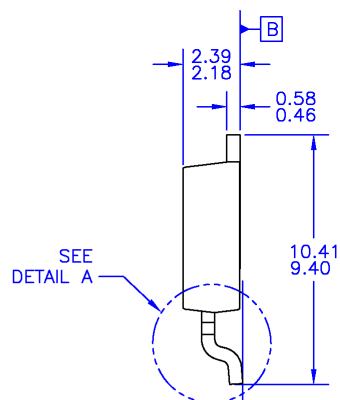
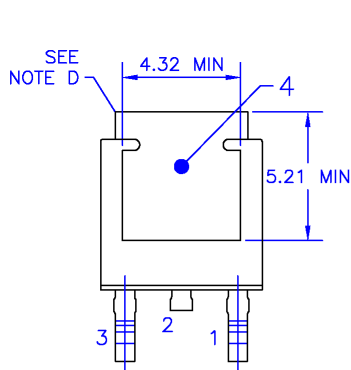
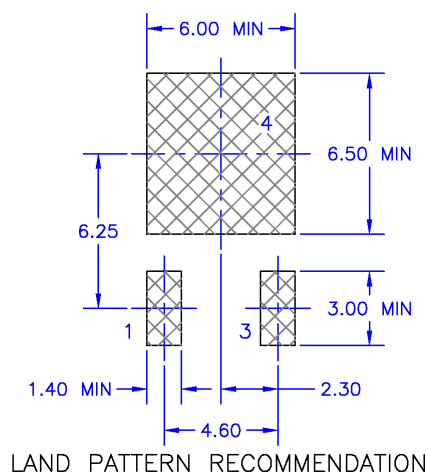
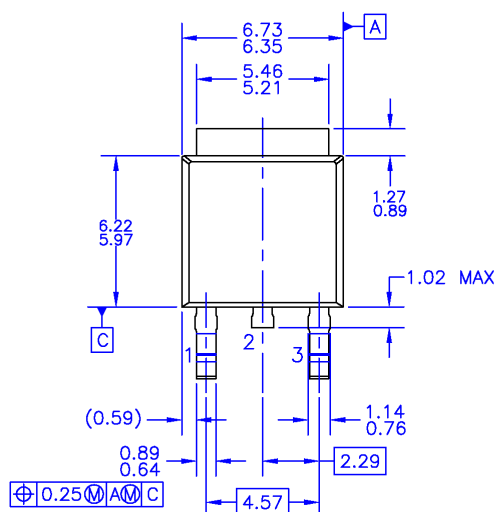


# Peak Diode Recovery dv/dt Test Circuit & Waveforms



# Mechanical Dimensions

## D-PAK



- NOTES: UNLESS OTHERWISE SPECIFIED
- A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE C, VARIATION AA.
  - B) ALL DIMENSIONS ARE IN MILLIMETERS.
  - C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
  - D) HEAT SINK TOP EDGE COULD BE IN CHAMFERED CORNERS OR EDGE PROTRUSION.
  - E) PRESENCE OF TRIMMED CENTER LEAD IS OPTIONAL.
  - F) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
  - G) LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD TO220P1003X238-3N.
  - H) DRAWING NUMBER AND REVISION: MKT-T0252A03REV8

Dimensions in Millimeters



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|                                                                                   |                                                 |                                       |                                                                                     |
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| AccuPower™                                                                        | F-PFS™                                          | PowerXS™                              | SYSTEM GENERAL®*                                                                    |
| AX-CAP®*                                                                          | FRFET®                                          | Programmable Active Droop™            | TinyBoost™                                                                          |
| BitSiC™                                                                           | Global Power ResourceSM                         | QFET®                                 | TinyBuck™                                                                           |
| Build it Now™                                                                     | Green Bridge™                                   | QS™                                   | TinyCalc™                                                                           |
| CorePLUS™                                                                         | Green FPS™                                      | Quiet Series™                         | TinyLogic®                                                                          |
| CorePOWER™                                                                        | Green FPS™ e-Series™                            | RapidConfigure™                       | TINYOPTO™                                                                           |
| CROSSVOLT™                                                                        | Gmax™                                           |                                       | TinyPower™                                                                          |
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| Current Transfer Logic™                                                           | IntelliMAX™                                     |                                       | TinyWire™                                                                           |
| DEUXPEED®                                                                         | ISOPLANAR™                                      | Saving our world, 1mW/W/kW at a time™ | TranSiC®                                                                            |
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| Fairchild Semiconductor®                                                          | MillerDrive™                                    | SuperFET™                             | Ultra FRFET™                                                                        |
| FACT Quiet Series™                                                                | MotionMax™                                      | SuperSOT™-3                           | UniFET™                                                                             |
| FACT®                                                                             | mWSaver™                                        | SuperSOT™-6                           | VCX™                                                                                |
| FAST®                                                                             | OptoHit™                                        | SuperSOT™-8                           | VisualMax™                                                                          |
| FastvCore™                                                                        | OPTOLOGIC®                                      | SupreMOS®                             | VoltagePlus™                                                                        |
| FETBench™                                                                         | OPTOPLANAR®                                     | SyncFET™                              | XS™                                                                                 |

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| Preliminary              | First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |
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